

The KATRIN Forward Beam Monitor Detector

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- Motivation
- Mounting position and mechanical integration
- Detector technology
- Test setup & first results
- Summary & Outlook

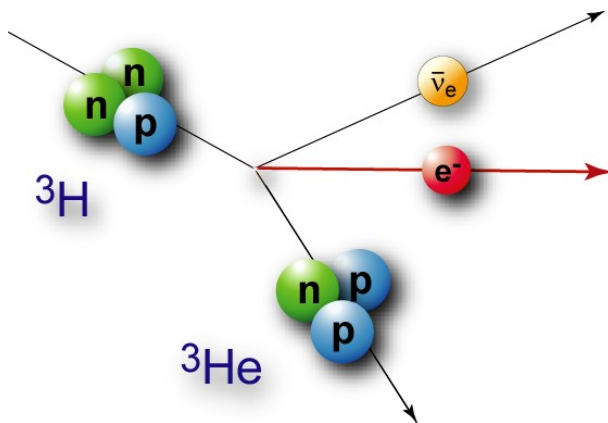
Introduction: KATRIN objective

Model independent neutrino mass from tritium β -decay kinematics

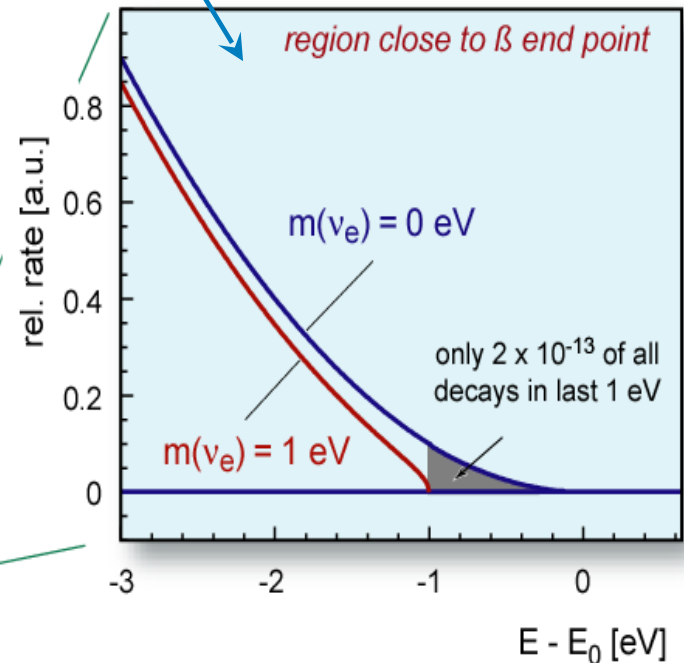
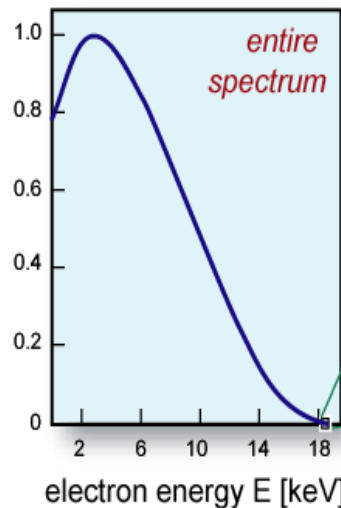
Sensitivity on m_ν : 0.2 eV

Only assumption: relativistic energy-momentum relation

$$\frac{d\Gamma_i}{dE} = C p (E + m_e) (E_0 - E) \sqrt{(E_0 - E)^2 - m_i^2} F(E) \theta(E_0 - E - m_i)$$



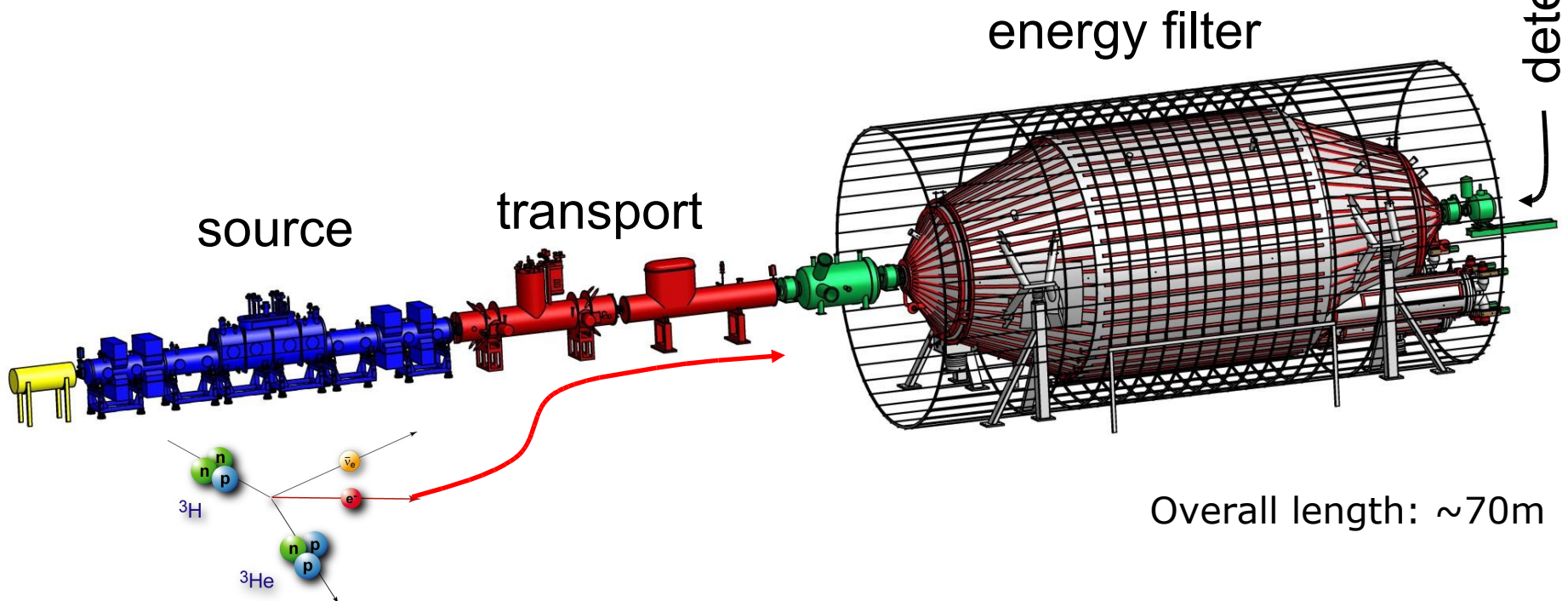
${}^3\text{H}$: $E_0 = 18.6 \text{ keV}$
 $T_{1/2} = 12.3 \text{ y}$



Introduction: KATRIN experimental setup

Main components:

- High-luminosity gaseous tritium source (1.7×10^{11} Bq)
- Two electrostatic retarding spectrometers (MAC-E-filters)
- Main detector



Motivation: Source design & properties

$$\text{Source strength } N(T_2) = A_S * \rho d * \epsilon_T$$

A_S = source area
 ρd = column density
 ϵ_T = tritium purity

Optimized source design parameters:

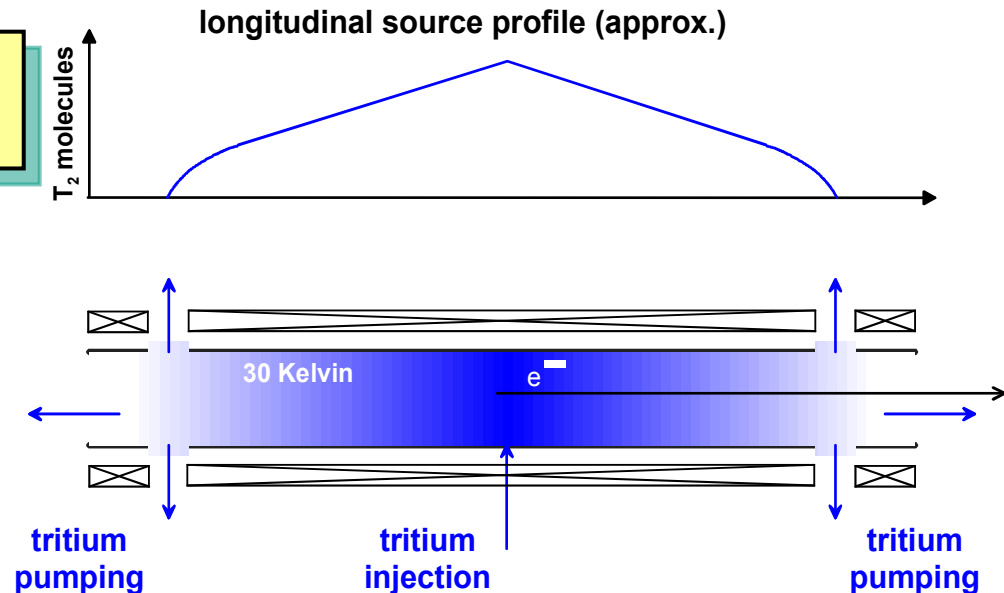
- $\rho d = 5 * 10^{17} \text{ cm}^{-2}$ (= 86% of maximum count rate of non-scattered electrons)
- $A_S = 53 \text{ cm}^2$, $B = 3.6 \text{ T}$
- $\epsilon_T = 95\%$

→ required tritium gas injection:
1.8 mbar l/s = 160 l/day

Source stability requirements:

ρd needs to be stable →

- $\Delta \epsilon_T / \epsilon_T < 0.002$
- $\Delta T / T < 0.002$
- $\Delta p_{inj} / p_{inj}, \Delta p_{ex} / p_{ex} < 0.002$



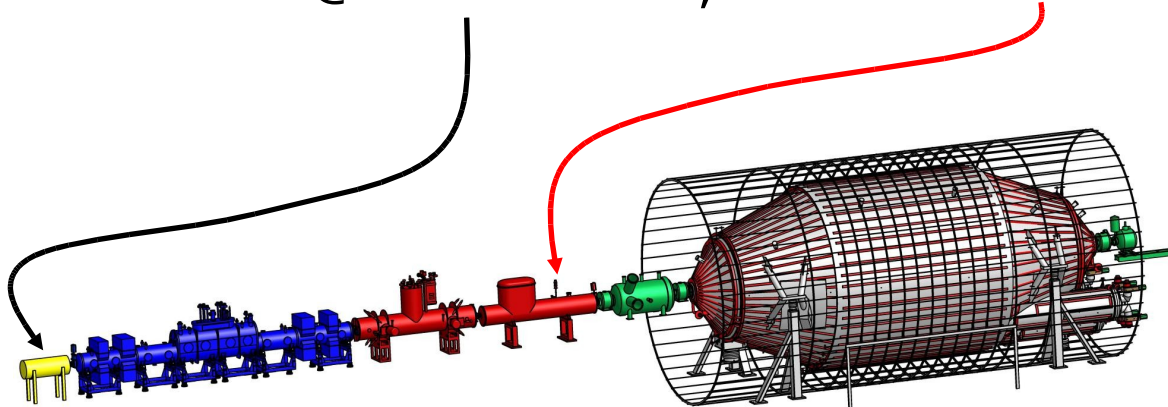
Source parameters and their monitoring

- Source stability @ 0.1% level is very challenging
- **Critical parameter: column density ρd** , mainly defined by
 - Source temperature (27-30 K) +/- 30 mK
 - Tritium inlet rate
 - Tritium purity (isotopic mixture)

inelastic scattering
→ modified spectrum

Monitoring concepts:

- Tritium purity: Laser Raman spectroscopy
- Column density: rear E-gun not
- Tritium activity: reduced spectrometer voltage, real-time
monitor detector @ rear section, monitor detector @ CPS



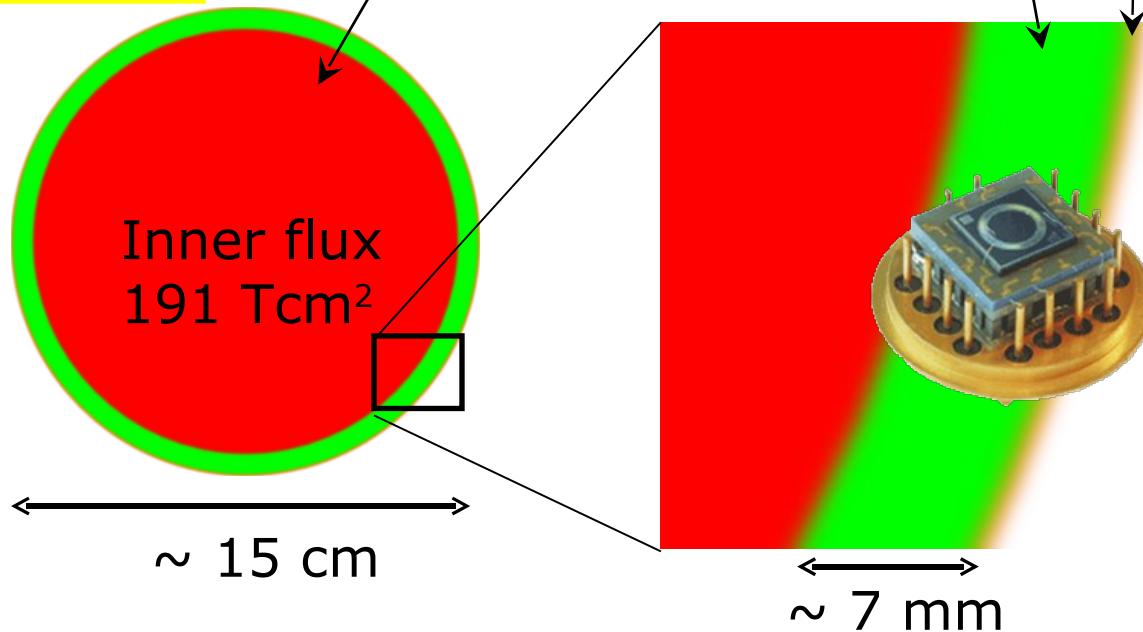
Beam dimensions @ mounting place

Expected count rate:

$1.3 \cdot 10^6$ counts / (s mm²)

→ very small detector
(< 1 mm²)

Total flux:
229 Tcm²



Inner flux
191 Tcm²

~ 15 cm

$B_{av} \sim 1.1$ T

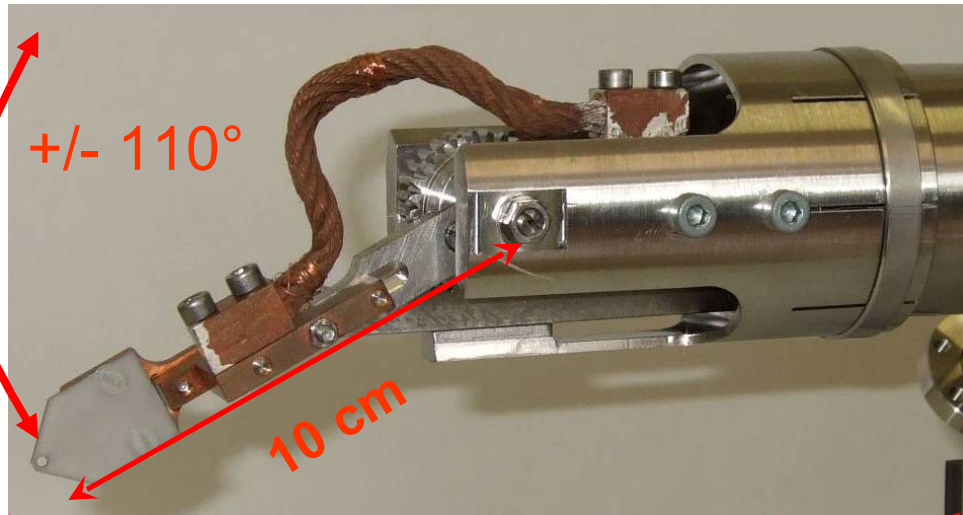
Main detector area

Monitoring area

Wall inter-
actions possible

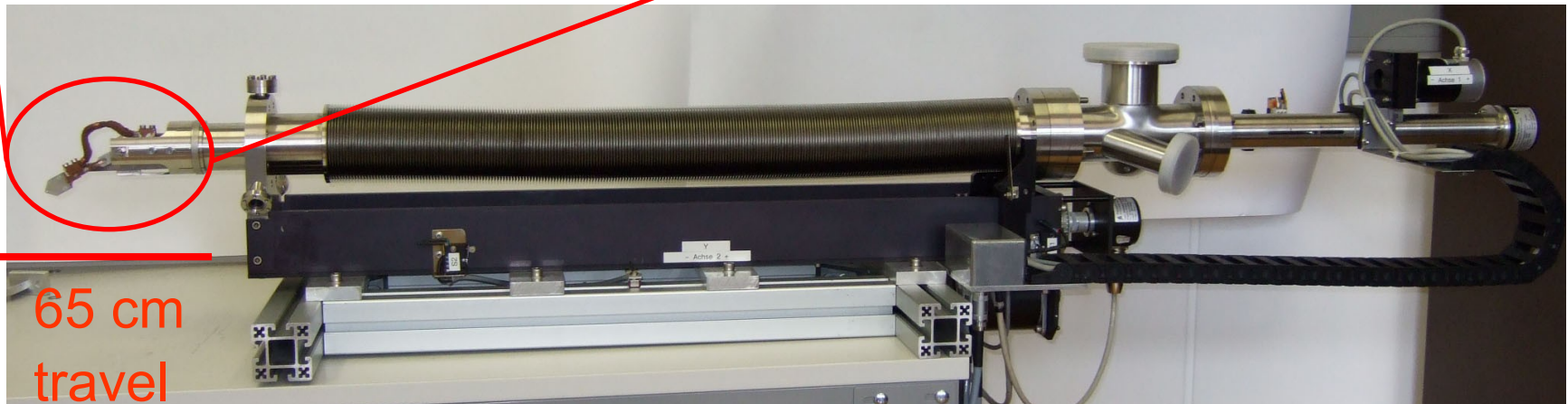
~ 7 mm

Mechanical integration



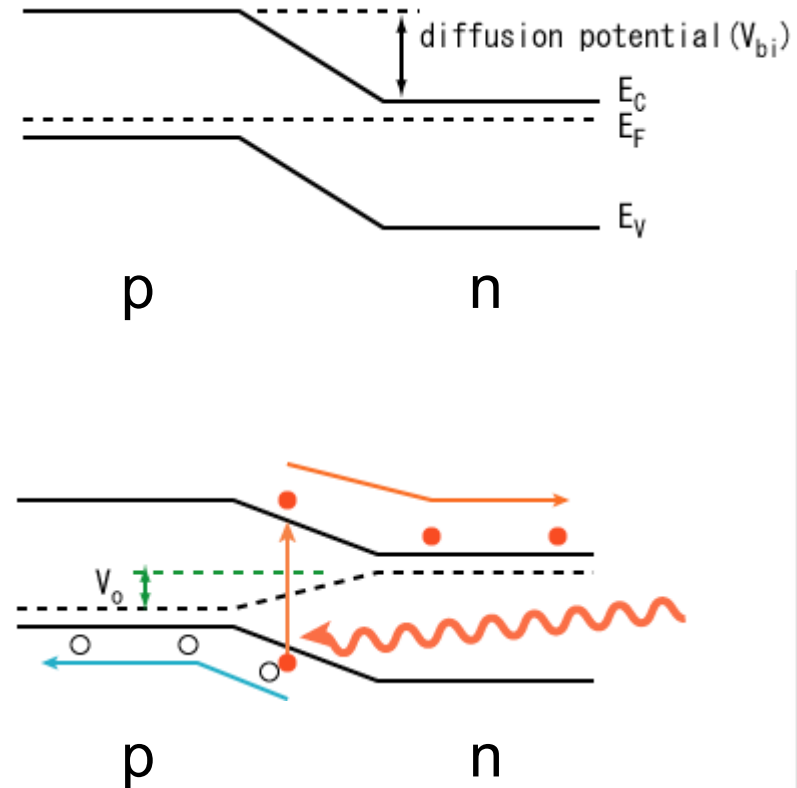
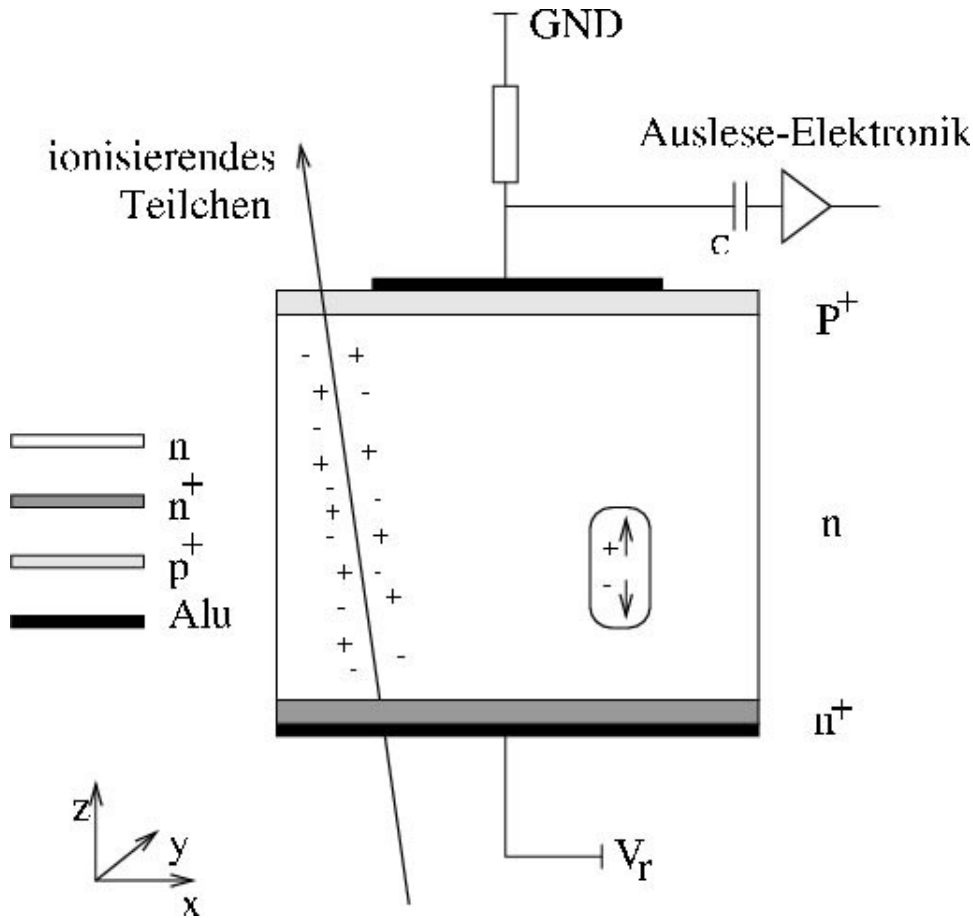
2-D manipulator:

- Two linear motions combined via gear mechanism
- Motorized positioning
- Flexible cooling braid
- Platform for detector element & preamp
- Rotary encoders measuring position

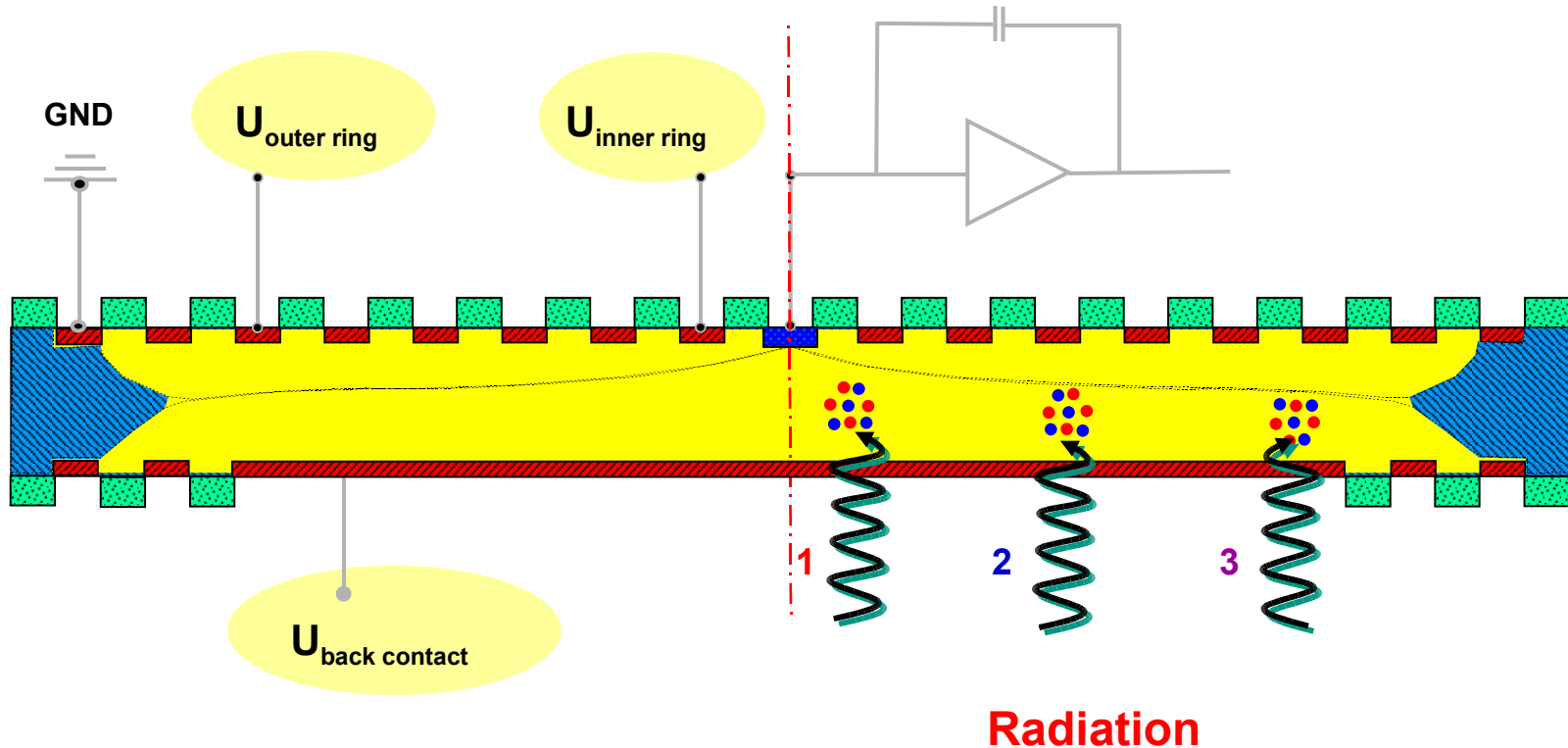


Detector technology

Reverse biased p-n junction (diode)

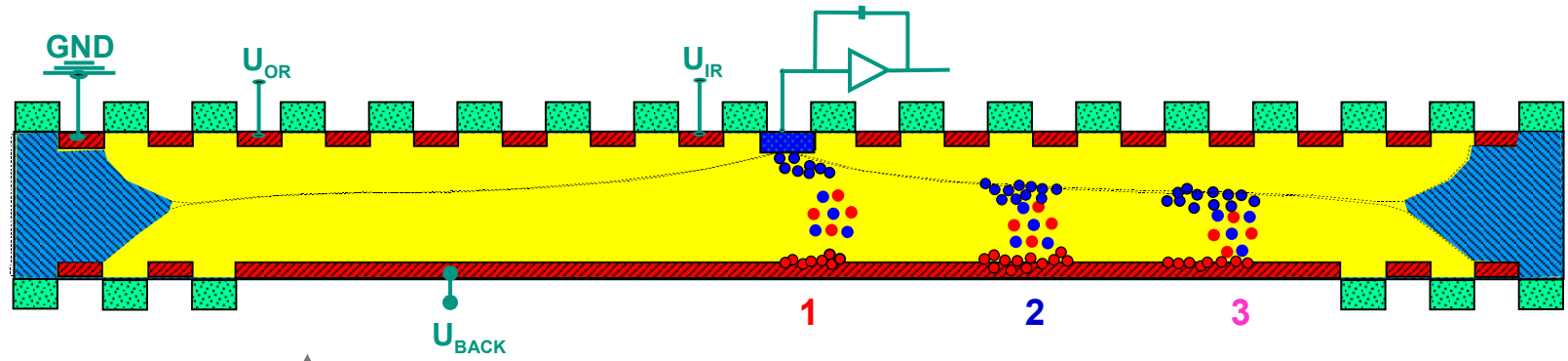


Silicon drift detector (SDD)



Animation: KETEK

Silicon drift detector (SDD)

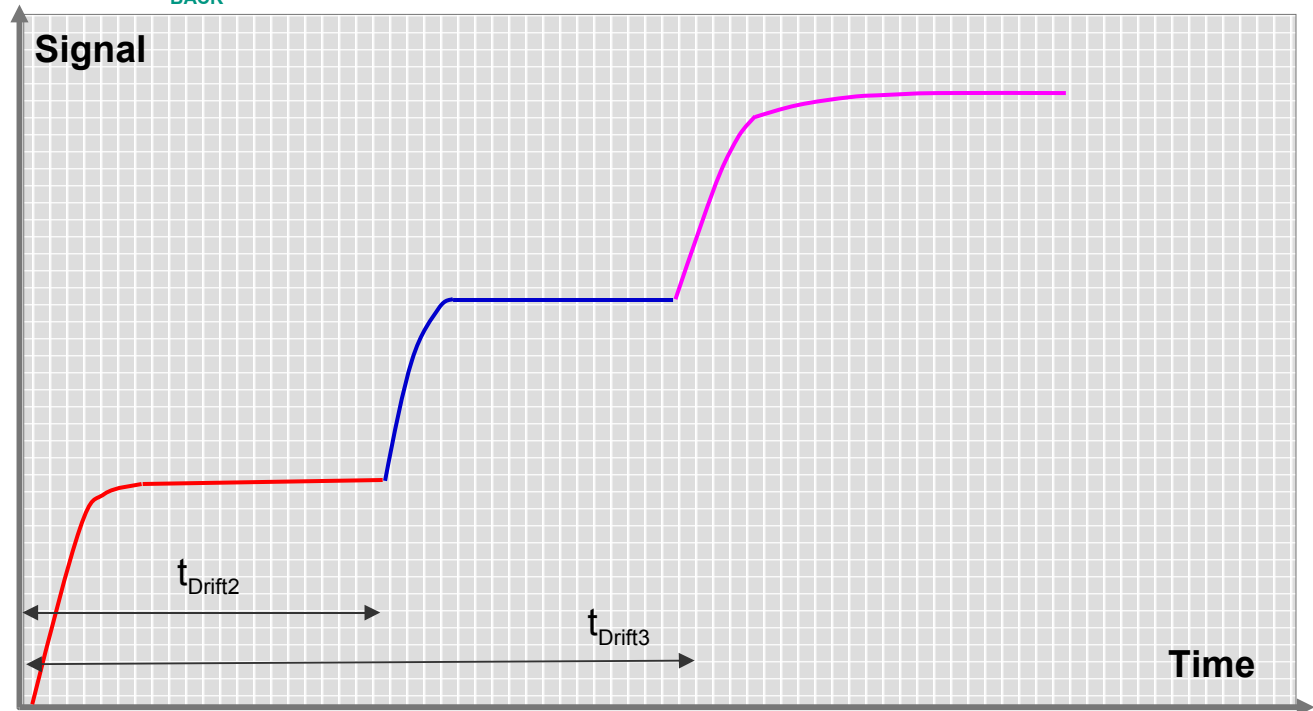


Charge
Collection:

Event 1 signal 1

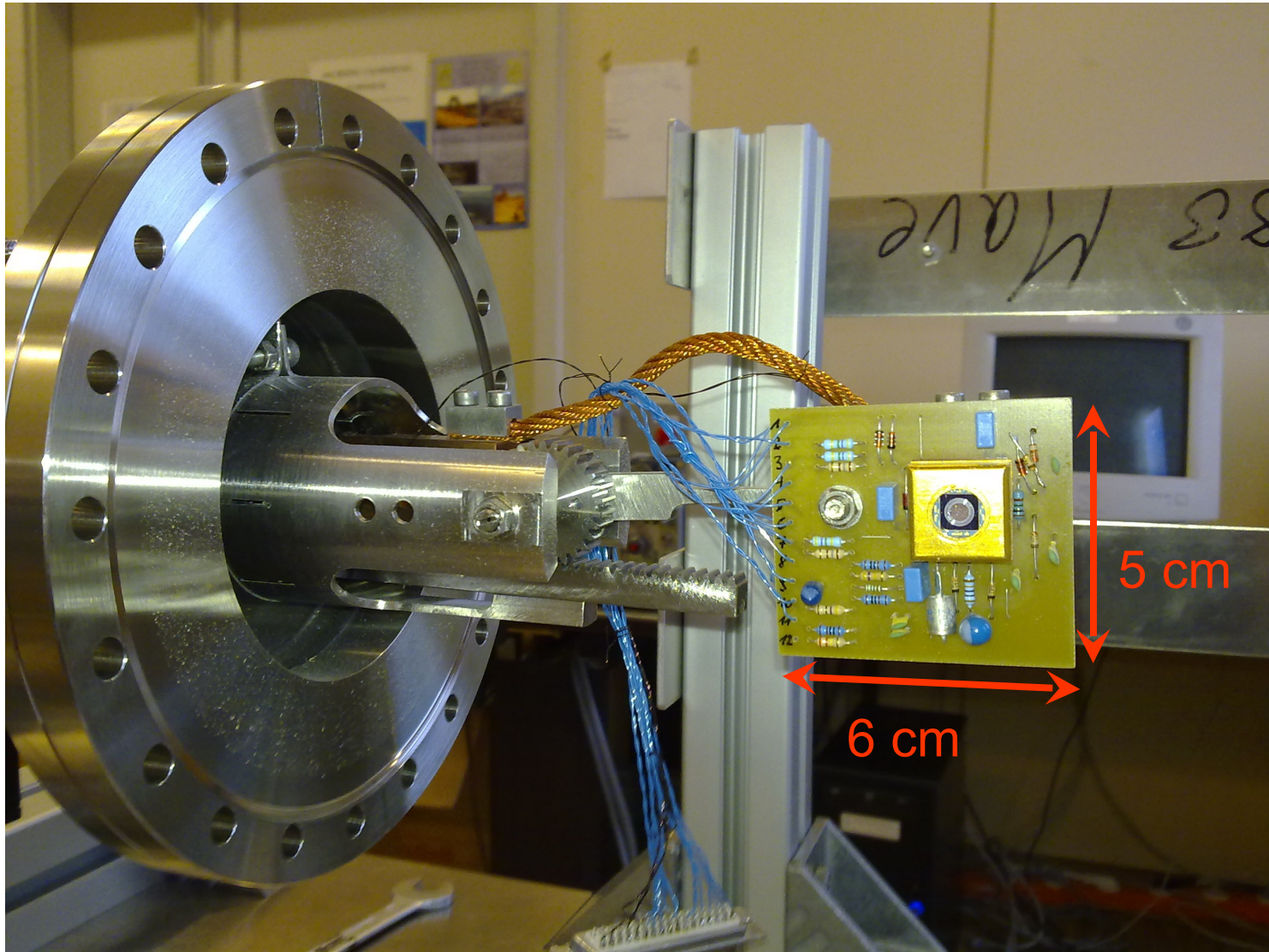
Event 2 signal 2

Event 3 signal 3

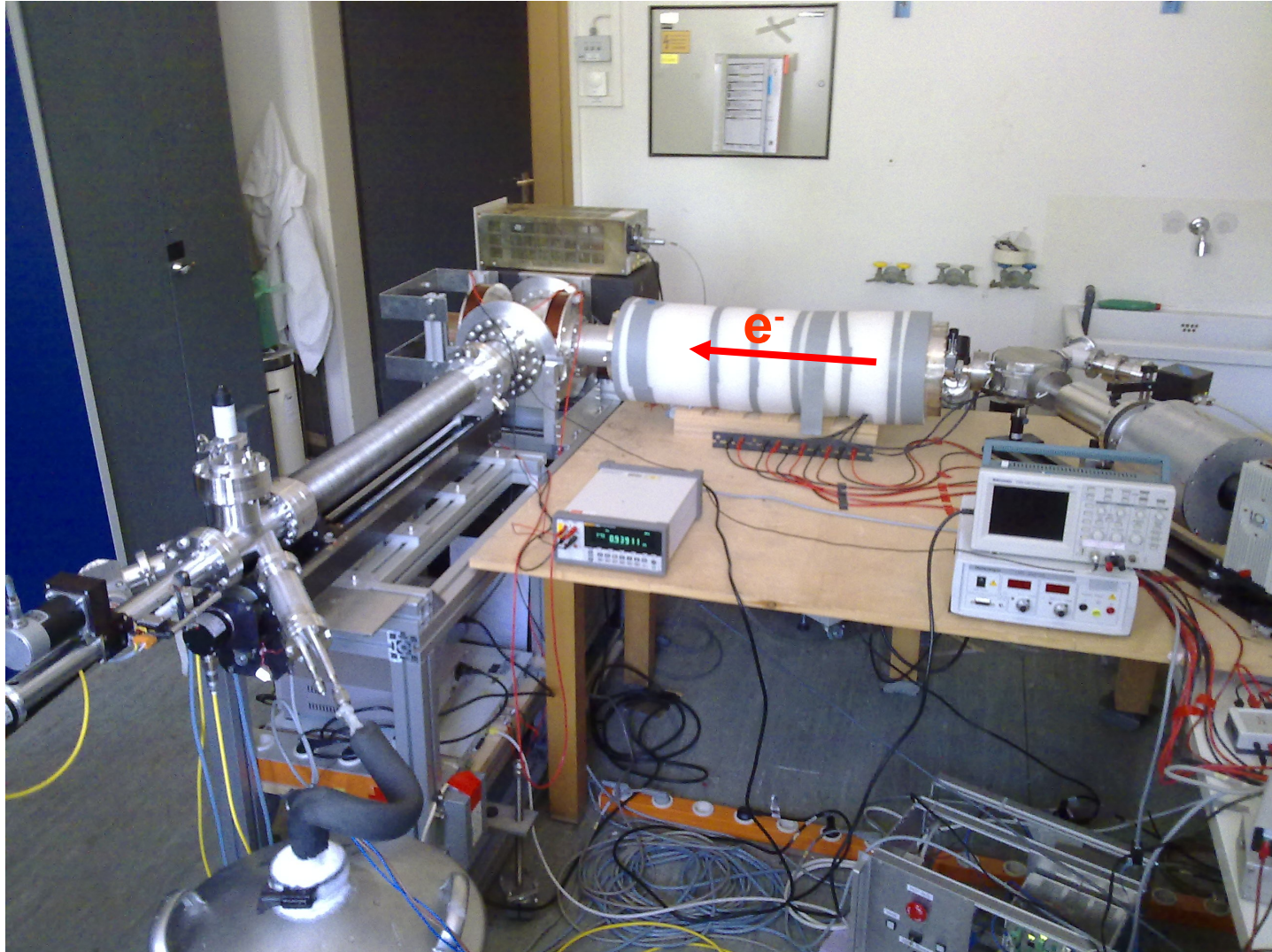


Animation: KETEK

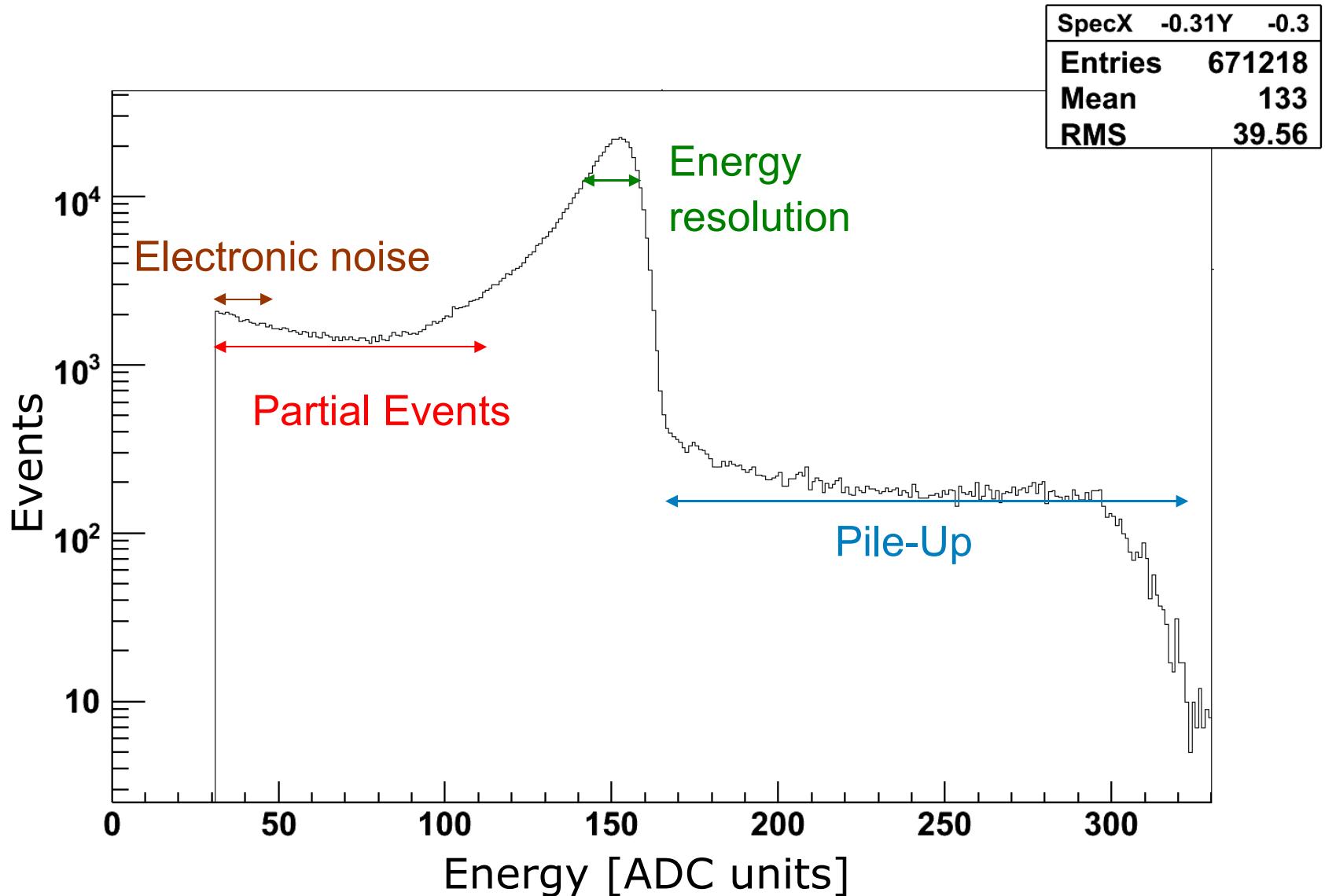
SDD Detector prototype



Electron-gun testing environment



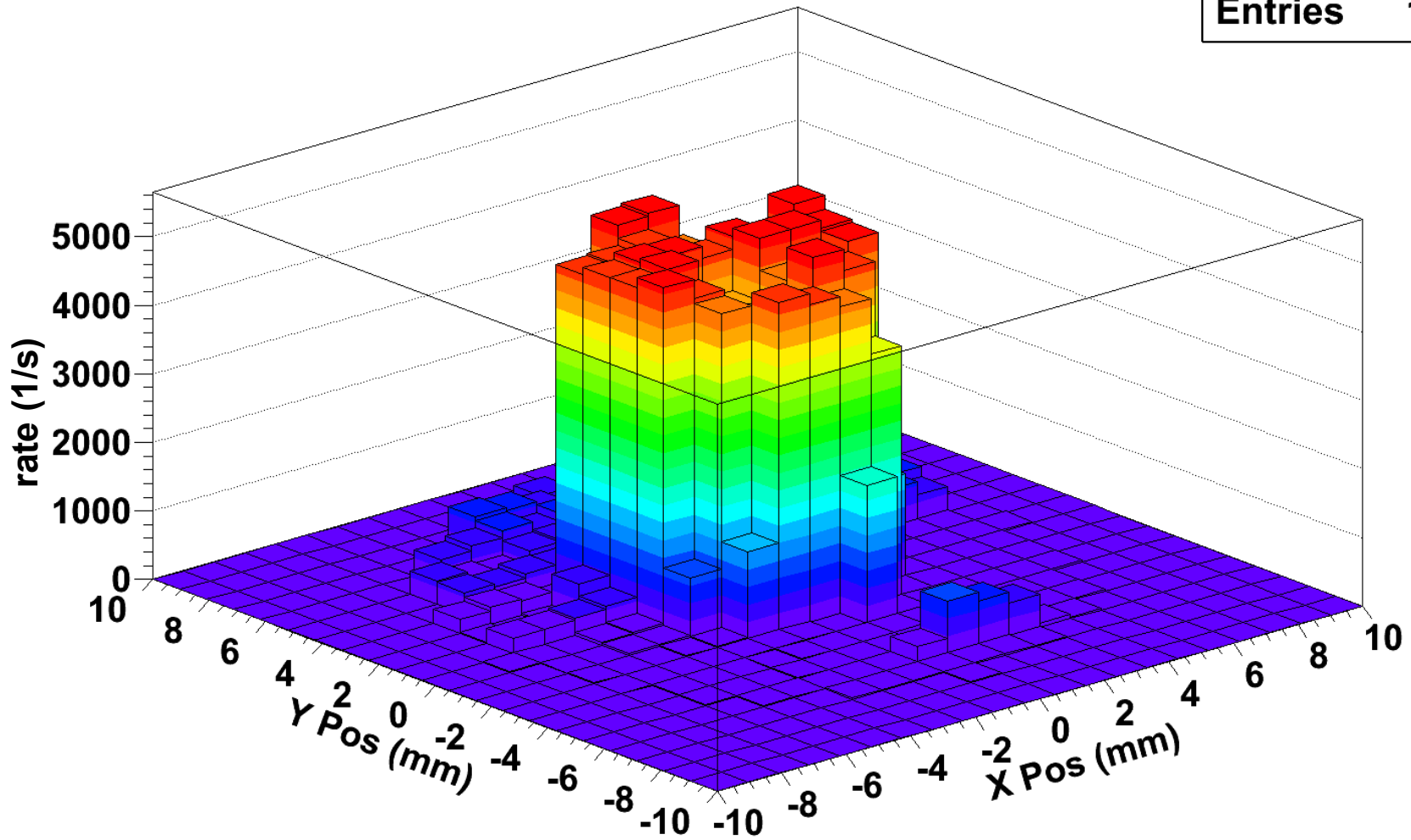
Example spectrum: 7 keV Electrons on SDD



E-Gun results – 2D beam scan

activity

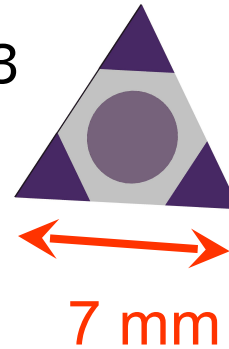
Entries 197



Next steps: PIN diode

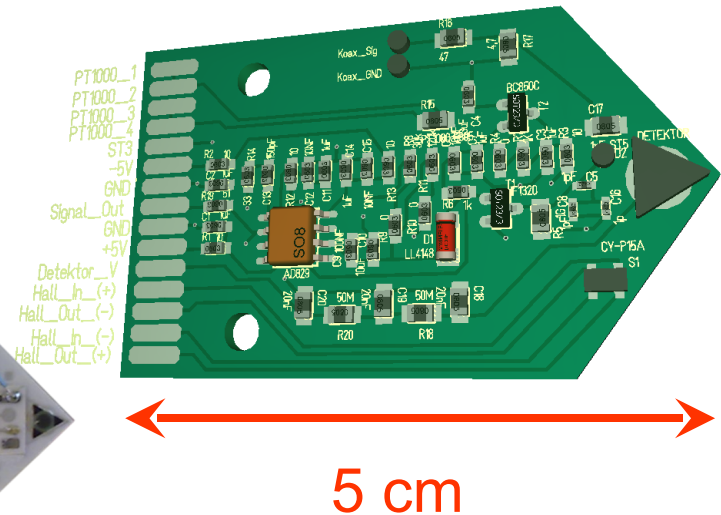
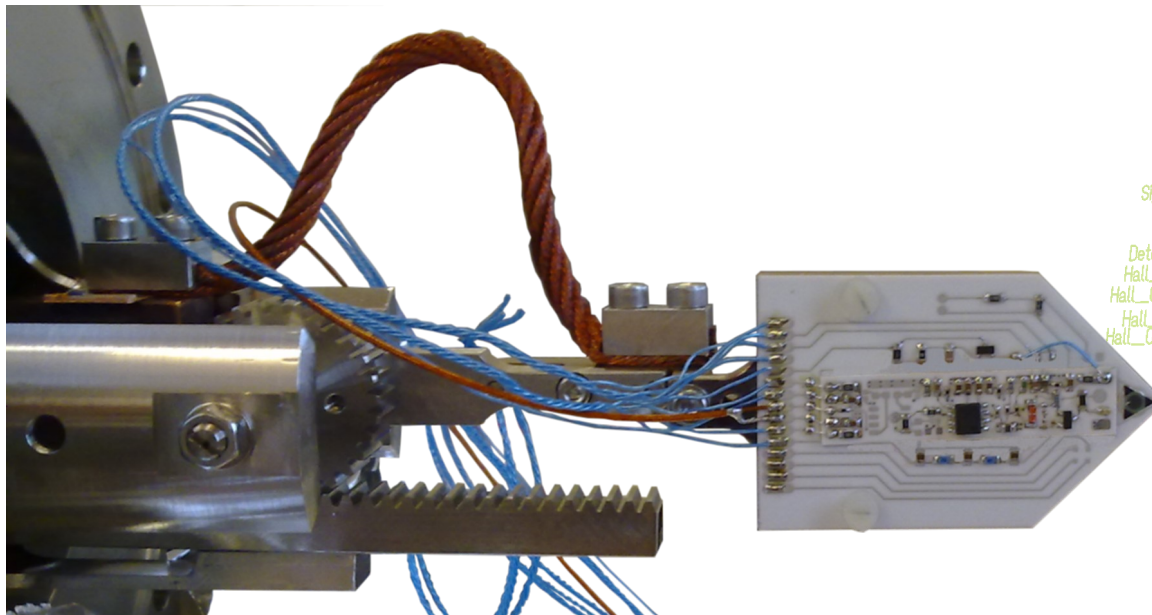
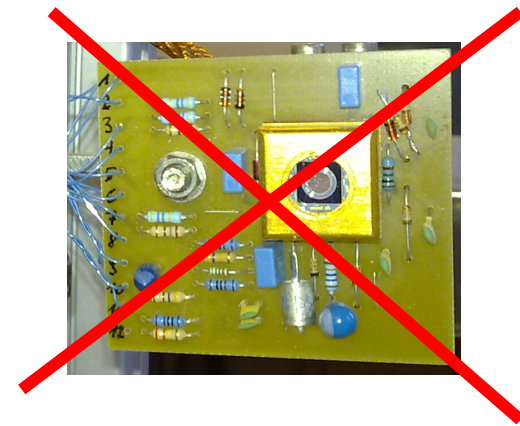
Test structure:

Micron Semiconductor MSD0013



Properties:

- 140 μm thickness
- 3 mm^2 active area, ~ 3.5 pF
- 100 nm dead layer



Summary:

- Detector design concept approved
- Full beam cross section can be probed
- Detector prototypes tested, proved to measure electrons with energies down to 2 keV and rates of ~ 40000 events/s

Outlook:

- Selection SDD / PIN diode
- Preamplifier optimization
- Approval of ultrahigh vacuum compatibility
- Tests at count rates ~ 100 kHz
- DAQ upgrade

Ende